# **UNR5174G**

## Silicon PNP epitaxial planar type

#### For digital circuits

#### ■ Features

- High forward current transfer ratio h<sub>FE</sub>
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through tape packing and magazine packing

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-50	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-50	V	
Collector current	$I_C$	-100	mA	
Total power dissipation	$P_{T}$	150	mW	
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	$T_{stg}$	-55 to +150	°C	

### ■ Package

- Code SMini3-F2
- Marking Symbol: 7P
- Pin Name
  - 1: Base
  - 2: Emitter
  - 3: Collector

#### ■ Internal Connection

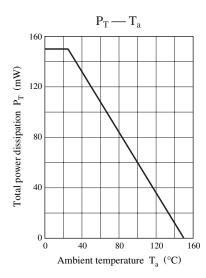
$$\begin{array}{c} R_1 \\ (10 \text{ k}\Omega) \\ B \circ \longrightarrow W \\ \hline R_2 \\ (47 \text{ k}\Omega) \end{array}$$

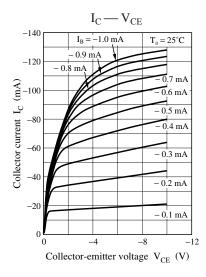
### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

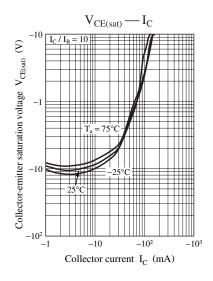
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	$I_{\rm C} = -10 \; \mu \text{A}, \; I_{\rm E} = 0$	-50			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-50			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = -50 \text{ V}, I_E = 0$			- 0.1	μΑ
Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = -50 \text{ V}, I_{B} = 0$			- 0.5	
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = -6 \text{ V}, I_C = 0$			- 0.2	mA
Forward current transfer ratio	$h_{FE}$	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	80			_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			- 0.25	V
Output voltage high-level	V <sub>OH</sub>	$V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	-4.9			V
Output voltage low-level	V <sub>OL</sub>	$V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			- 0.2	V
Input resistance	R <sub>1</sub>		-30%	10	+30%	kΩ
Resistance ratio	$R_1 / R_2$		0.17	0.21	0.25	_
Forward voltage	$V_{\rm F}$	$I_F = 100 \text{ mA}$		0.95	1.20	V
Transition frequency	$f_T$	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz

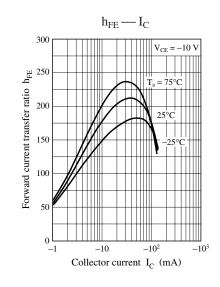
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

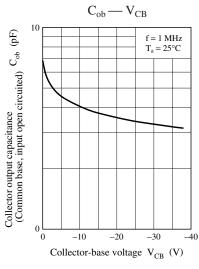
## **Panasonic**

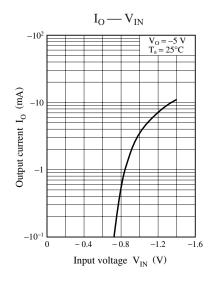


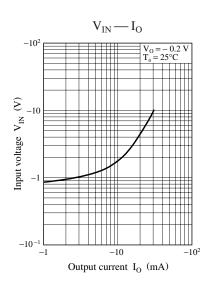






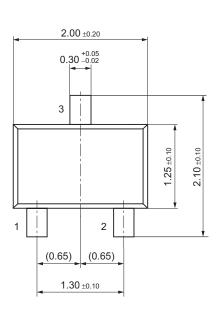


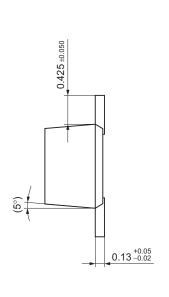


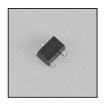


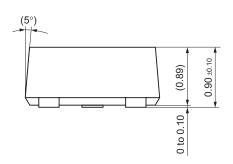
2 SJH00217AED

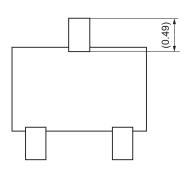
SMini3-F2 Unit: mm











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